

# BGSA147ML10

## Ultra Low Resistance Antenna Tuning SP4T

### Features

- Designed for high-linearity antenna tuning switching and RF tuning applications
- Ultra low  $R_{ON}$  resistance of 0.8  $\Omega$  at each RF port in ON state
- Individually controlled reflective open or short to ground OFF ports to eliminate unwanted antenna resonances
- Low C<sub>OFF</sub> capacitance of 155 fF at each port in OFF state
- High RF operating voltage handling above 45 V in OFF state
- MIPI RFFE 2.1 compliant control interface
- External USID\_sel pin enabling 3 default USID addresses
- No RF parameter change within supply voltage range
- No blocking capacitors required if no DC applied on the RF lines
- No power supply decoupling required
- Small form factor 1.1 mm x 1.5 mm x 0.39 mm (MSL1, 260°C per JEDEC J-STD-020)
- RoHS and WEEE compliant package

### **Potential Applications**

- Impedance Tuning
- Antenna Tuning
- Inductance Tuning
- Tunable Filters

#### **Product Validation**

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

### **Block diagram**

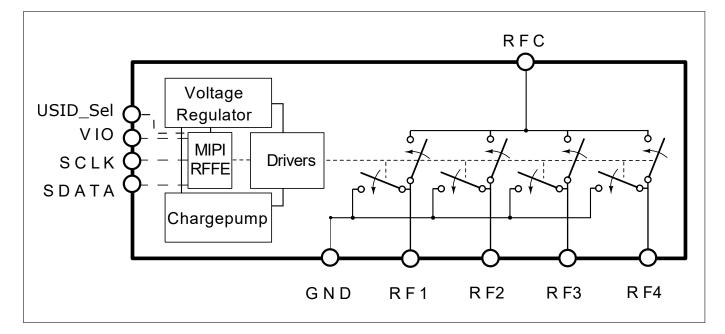






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### Features

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### Description

The BGSA147ML10 is a Single-Pole Four Throws (SP4T) Antenna Tuning switch optimized for RF applications up to 7.125 GHz. Its MIPI RFFE digital control interface allows easy implementation and best flexibility when operated in cellular mobile RF Front-End designs.

The BGSA147ML10 is made of 4 ultra-low On resistance / low Off capacitance series switches and 4 shunt to ground switches enabling on-demand open-reflective or short-reflective OFF ports behaviour. This last feature is of great value to reduce antenna engineer development time in case of unwanted antenna resonance or to improve antenna efficiency with less component tuning effort.

Unlike GaAs RF switches, highly linear RF performance is reached at all signal levels within the operating conditions. High RF voltage ruggedness and individually programmable shunt to ground switches on each RF throw make BGSA147ML10 particularly efficient for switching inductors and capacitors in RF matching and Antenna Tuning circuits.

Туре	Marking	Package	Ordering Information
BGSA147ML10	A7	TSLP-10-3	BGSA 147ML10 E6327



**Maximum Ratings** 

### 2 Maximum Ratings

Parameter	Symbol	Symbol Values		Unit	Note / Test Condition		
		Min.	Тур.	Max.	_		
Frequency Range	f	0.4	-	7.125	GHz	1)	
RFFE Supply voltage <sup>2)</sup>	V <sub>IO</sub>	-0.3	-	2.2	V	Only for infrequent and short duration time periods	
Storage temperature range	T <sub>STG</sub>	-55	-	150	°C	-	
RF peak voltage	V <sub>RF_max</sub>	-	-	50	V	Short term peaks (1µs in 0.1% duty cycle), exceeding typical linearity, Ron and Coff param- eters, in Isolation mode, test condition schematic in Fig. 1	
ESD robustness, CDM <sup>3)</sup>	V <sub>ESDcdm</sub>	-1	-	+1	kV		
ESD robustness, HBM <sup>4)</sup>	V <sub>ESDHBM</sub>	-2	-	+2	kV		
Junction temperature	Tj	-	_	125	°C	-	
Thermal resistance junction - soldering point	R <sub>thJS</sub>	-	-	80	K/W	-	
Maximum DC-voltage on RF-Ports and RF- Ground	V <sub>RFDC</sub>	0	-	0	V	No DC voltages allowed on RF- Ports	
RFFE Control Voltage Levels	V <sub>SCLK</sub> , V <sub>SDATA</sub> , V <sub>USID_SEL</sub>	-0.7	-	V <sub>IO</sub> +0.7 (max. 2.2)	V	-	

#### **Table 1: Maximum Ratings Table** at $T_A = 25 \,^{\circ}$ C, unless otherwise specified

<sup>1)</sup> Switch has a low-pass response. For higher frequencies, losses have to be considered for their impact on thermal heating. The DC voltage at RF ports V<sub>RFDC</sub> has to be 0V.

<sup>2)</sup> Note: Consider any ripple voltages on top of  $V_{IO}$ . A high RF ripple at the  $V_{IO}$  can exceed the maximum ratings by  $V_{IO} = V_{DC} + V_{Ripple}$ .

<sup>3)</sup> Field-Induced Charged-Device Model ANSI/ESDA/JEDEC JS-002. Simulates charging/discharging events that occur in production equipment and processes. Potential for CDM ESD events occurs whenever there is metal-to-metal contact in manufacturing.

 $^{4)}$  Human Body Model ANSI/ESDA/JEDEC JS-001 (R=1,5 k $\!\Omega,$  C=100 pF).

Warning: Stresses above the max. values listed here may cause permanent damage to the device. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit. Exposure to conditions at or below absolute maximum rating but above the specified maximum operation conditions may affect device reliability and life time. Functionality of the device might not be given under these conditions.



**Maximum Ratings** 

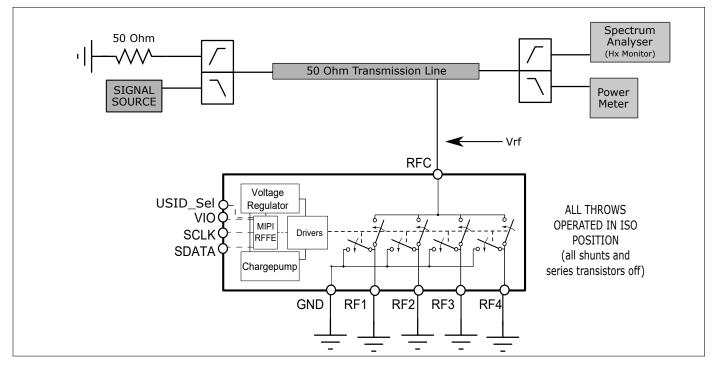


Figure 1: RF operating voltage measurement configuration - OFF mode

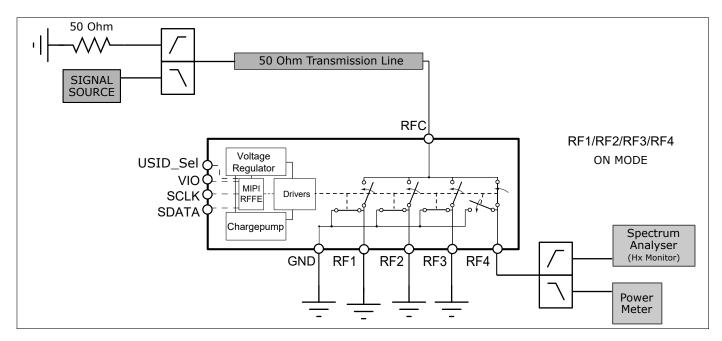


Figure 2: RF operating and Harmonics generation measurement configuration - RFx ON mode (RF4 as example)



**DC Characteristics** 

## **3 DC Characteristics**

### Table 2: DC Characteristics at $T_A = -40 \degree$ C to 85 $\degree$ C

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
RFFE supply voltage	V <sub>IO</sub>	1.65	1.8	1.95	V	-
RFFE input high voltage <sup>1</sup>	V <sub>IH</sub>	0.7*V <sub>IO</sub>	-	V <sub>IO</sub>	V	-
RFFE input low voltage <sup>1</sup>	V <sub>IL</sub>	0	-	0.3*V <sub>IO</sub>	V	-
RFFE output high voltage <sup>1</sup>	V <sub>OH</sub>	0.8*V <sub>IO</sub>	-	V <sub>IO</sub>	V	-
RFFE output low voltage <sup>1</sup>	V <sub>OL</sub>	0	-	0.2*V <sub>IO</sub>	V	-
RFFE control input capacitance	C <sub>Ctrl</sub>	-	-	2	pF	-
DEEE supply surront		-	2	-	μΑ	VIO Shutdown Mode
RFFE supply current	1 <sub>VIO</sub>	-	22	35	μA	Idle State, no RF Power

<sup>1</sup>SCLK and SDATA



**RF Small Signal Characteristics** 

## 4 RF Small Signal Characteristics

### **Table 3: Parametric specifications**

Parameter	Symbol	mbol Values			Unit	STATE / Notes
		Min.	Тур.	Max.		
Series switch	R <sub>ON_Series</sub>	-	0.8	0.85	Ω	
ON DC resistance						$T = 2 \mathbf{f}^{\circ} \mathbf{C}$
Series switch	R <sub>OFF_Series</sub>	250	-	-	kΩ	$T_A = 25 ^{\circ}\text{C},$
OFF DC resistance						$Z_0 = 50 \Omega$
Shunt to GND switch	R <sub>ON_Shunt</sub>		5.8	7	Ω	
ON DC resistance						
Shunt to GND switch	R <sub>OFF_Shunt</sub>	250	-	-	kΩ	
OFF DC resistance						
RFx to RFc	C <sub>OFF</sub> <sup>(1)</sup>	-	155	170	fF	
OFF capacitance, 1 GHz						

<sup>1)</sup> OFF capacitance calculated from Y21 parameters, shunt OFF.



### **RF Small Signal Characteristics**

### Table 4: RF electrical parameters, OFF port shunts switches open

Parameter	Symbol		Values			STATE / Notes
			Тур.	Max.		
Insertion Loss: RFx to RFC <sup>(1,2,3,4)</sup>			1	·		
600 - 960 MHz			0.1	0.3	dB	
1400 - 1700 MHz			0.25	0.5	dB	_
1710 - 2169 MHz			0.35	0.6	dB	$V_{IO} = 1.65 - 1.95 V$ ,
2170 - 2690 MHz	IL <sub>SP4T</sub>		0.5	0.9	dB	$\int Z_0 = 50 \Omega$ at all RF-ports,
3300 - 4200 MHz			1.2	1.8	dB	$T_{A} = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$
4400 - 5000 MHz			1.7	2.3	dB	-
5150 - 5925 MHz			2.1	2.9	dB	-
5925 - 7125 MHz			2.5	3.9	dB	_
Return Loss: RF1, RF2, RF3, RF4 o	or RFC <sup>(1,2,3)</sup>	1				
600 - 960 MHz		17	21		dB	
1400 - 1700 MHz		13	16		dB	-
1710 - 2169 MHz		11	14		dB	$V_{IO} = 1.65 - 1.95 V$ ,
2170 - 2690 MHz	RL <sub>SP4T</sub>	9	13		dB	$Z_0 = 50 \Omega$ at all RF-ports,
3300 - 4200 MHz		6	9		dB	$T_{A} = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$
4400 - 5000 MHz		5	8		dB	-
5150 - 5925 MHz		4	7		dB	-
5925 - 7125 MHz		4	6		dB	_
Isolation: RFx to RFC <sup>(1,2,3,4)</sup>						
600 - 960 MHz		19	23		dB	
1400 - 1700 MHz		15	17		dB	-
1710 - 2169 MHz		13	16		dB	$V_{IO}$ = 1.65 - 1.95 V,
2170 - 2690 MHz	ISO <sub>OFF</sub>	12	14		dB	$Z_0 = 50 \Omega$ at all RF-ports,
3300 - 4200 MHz		10	12		dB	$T_A = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$
4400 - 5000 MHz		9	11		dB	
5150 - 5925 MHz		9	11		dB	
5925 - 7125 MHz		9	11		dB	

<sup>1)</sup> Valid for all RF power levels, no compression behavior

<sup>2)</sup>On application board without any matching components

<sup>3)</sup>Shunts in OFF Mode  $^{4)}x = 1, 2, 3, 4$ 



### **RF Small Signal Characteristics**

### Table 5: RF electrical parameters, OFF port shunts switches closed

Parameter	Symbol		Values			STATE / Notes	
		Min. Typ. M		Max.			
Insertion Loss: RFx to RFC <sup>(1,2,3,4)</sup>					-		
600 - 960 MHz			0.1	0.2	dB		
1400 - 1700 MHz			0.2	0.35	dB	-	
1710 - 2169 MHz			0.3	0.5	dB	$V_{IO} = 1.65 - 1.95 V$ ,	
2170 - 2690 MHz	IL <sub>SP4T</sub>		0.4	0.8	dB	$Z_0 = 50 \Omega$ at all RF-ports,	
3300 - 4200 MHz			1.1	1.9	dB	$T_{A} = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$	
4400 - 5000 MHz			1.8	2.7	dB	-	
5150 - 5925 MHz			2.5	3.7	dB	-	
5925 - 7125 MHz			3.3	5.3	dB	-	
Return Loss: RF1, RF2, RF3, RF4	or RFC <sup>(1,2,3)</sup>					1	
600 - 960 MHz		17	21		dB		
1400 - 1700 MHz		12	16		dB	-	
1710 - 2169 MHz		11	14		dB	$V_{IO} = 1.65 - 1.95 V$ ,	
2170 - 2690 MHz	RL <sub>SP4T</sub>	9	12		dB	$Z_0 = 50 \Omega$ at all RF-ports,	
3300 - 4200 MHz		5	8		dB	$T_{A} = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$	
4400 - 5000 MHz		4	6		dB	-	
5150 - 5925 MHz		3	5		dB	-	
5925 - 7125 MHz		3	5		dB	-	
Isolation: RFx to RFC <sup>(1,2,3,4)</sup>						1	
600 - 960 MHz		32	39		dB		
1400 - 1700 MHz		23	30		dB	-	
1710 - 2169 MHz		20	27		dB	$V_{IO} = 1.65 - 1.95 V$ ,	
2170 - 2690 MHz	ISO <sub>OFF</sub>	17	24		dB	$Z_0 = 50 \Omega$ at all RF-ports,	
3300 - 4200 MHz		12	18		dB	$T_{A} = -40 ^{\circ}\text{C} + 85 ^{\circ}\text{C}$	
4400 - 5000 MHz		10	16		dB		
5150 - 5925 MHz		9	14		dB	1	
5925 - 7125 MHz		8	13		dB		

<sup>1)</sup> Valid for all RF power levels, no compression behavior

<sup>2)</sup>On application board without any matching components

<sup>3)</sup>Shunts in ON Mode <sup>4)</sup>x = 1, 2, 3, 4



RF large signal parameter

## 5 RF large signal parameter

Parameter	Symbol		Values			Note / Test Condition
		Min.	Тур.	Max.	_	
RF Operating Voltage	V <sub>RF_opr</sub>	-	-	45	V	In Isolation mode, 900 MHz test condition schematic in Fig. 1
Harmonic Generation up to 1	5 GHz, all RF Po	orts				
Second Order Harmonics	P <sub>H2</sub>	-	-85	-80	dBm	26 dBm, 50 Ω, $f_0$ = 663 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-92	-88	dBm	26 dBm, 50 Ω, $f_0$ = 663 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-67	-60	dBm	35 dBm, 50 Ω, $f_0$ = 920 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-69	-66	dBm	35 dBm, 50 Ω, $f_0$ = 920 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-65	-61	dBm	33 dBm, 50 Ω, $f_0$ = 1910 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-70	-66	dBm	33 dBm, 50 Ω, $f_0$ = 1910 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-68	-64	dBm	29 dBm, 50 Ω, $f_0$ = 2690 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-74	-68	dBm	29 dBm, 50 Ω, $f_0$ = 2690 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-65	-58	dBm	29 dBm, 50 Ω, $f_0$ = 3600 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-76	-69	dBm	29 dBm, 50 Ω, $f_0$ = 3600 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-67	-64	dBm	29 dBm, 50 Ω, $f_0$ = 4400 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-77	-73	dBm	29 dBm, 50 Ω, $f_0$ = 4400 MHz
Second Order Harmonics	P <sub>H2</sub>	-	-68	-64	dBm	29 dBm, 50 Ω, $f_0$ = 5000 MHz
Third Order Harmonics	P <sub>H3</sub>	-	-77	-70	dBm	29 dBm, 50 Ω, $f_0$ = 5000 MHz
Intermodulation Distortion I	MD2					
IIP2, low	IIP2, l	110	121	-	dBm	UD2 conditions Tab. 7
IIP2, high	IIP2, h	115	125	-	dBm	IIP2 conditions Tab. 7
Intermodulation Distortion I	MD3					
IIP3	IIP3	72	78	-	dBm	IIP3 conditions Tab. 8

### Table 6: RF large signal specifications at $T_A = 25 \ ^{\circ}\text{C}$



RF large signal parameter

#### Table 7: IIP2 conditions table

Band	In-Band Frequency	Blocker Frequency 1	Blocker Power 1	Blocker Frequency 2	Blocker Power 2
	[MHz]	[MHz]	[dBm]	[MHz]	[dBm]
Band 1 Low	2140	1950	23	190	-15
Band 1 High	2140	1950	23	4090	-15
Band 5 Low	881.5	836.5	23	45	-15
Band 5 High	881.5	836.5	23	1718	-15

#### Table 8: IIP3 conditions table

Band	In-Band Frequency	Blocker Frequency 1	Blocker Power 1	Blocker Frequency 2	Blocker Power 2
	[MHz]	[MHz]	[dBm]	[MHz]	[dBm]
Band 1	2140	1950	23	1760	-15
Band 5	881.5	836.5	23	791.5	-15



**MIPI RFFE Specification** 

## 6 MIPI RFFE Specification

The MIPI RFFE interface is implemented according to the following specifications and documents:

- MIPI Alliance Specification for RF Front-End Control Interface version 2.1 18 December 2017
- MIPI Alliance Errata 01 for MIPI RFFE Specification Version v2.1 24 February 2019
- Qualcomm RFFE Vendor specification 80-N7876-1 Rev. Y (December 3, 2018)

#### **Table 9: MIPI Features**

Feature	Supported	Comment
MIPI RFFE 2.1 standard	Yes	Backward compatible to MIPI 2.0 standard
Register 0 write command sequence	Yes	
Register read and write command sequence	Yes	
Extended register read and write command sequence	Yes	
Support for standard frequency range operations for	Yes	Up to 26 MHz
SCLK		
Support for extended frequency range operations for	Yes	Up to 52 MHz
SCLK		
Longer Reach RFFE Bus Length Feature	Yes	
Programmable driver strength	Yes	Up to 80 pF
Programmable Group SID	Yes	
Programmable USID	Yes	
Trigger functionality	Yes	
Extended Triggers and Trigger Masks	Yes	
Broadcast / GSID write to PM TRIG register	Yes	
Reset	Yes	Via VIO, PM TRIG or software register
Status / error sum register	Yes	
Extended product ID register	Yes	
Revision ID register	Yes	
Group SID register	Yes	
USID select pin	Yes	USID selection See Tab. 10



### **MIPI RFFE Specification**

#### **Table 10: Default MIPI USID Selection**

Address	Symbol	External Conditon at USID Port
USID=0110	Addr6	to VIO
USID=0111	Addr7	Ground
USID=1001	Addr9	Floating <sup>1)</sup>

<sup>1)</sup> Total capacitance on the USID\_SEL pin must be <5 pF.

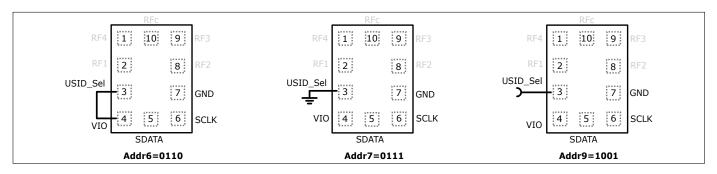


Figure 3: BGSA147ML10 USID\_Sel Pin Configuration

#### Table 11: Startup Behavior

Feature	State	Comment
Power status	Low power	Lower power mode after start-up
		Default power mode is HIGH
Trigger function	Enabled	Enabled after start-up. Programmable via behavior control register



**MIPI RFFE Specification** 

### Table 12: Switching Time Behavior

Parameter	Symbol		Values		Unit	STATE / Notes
		Min.	Тур.	Max.		
Power Up Settling Time	t <sub>PUP</sub>	-	9	15	μs	Time from Power Up plus Switch command 50% last SCLK falling edge to 90% RF-Signal, see Fig. 4
Switching Time	t <sub>sr</sub>	-	8	11	μs	Time switching between RF states 50% last SCLK falling edge to 90% RF-Signal, see Fig. 4

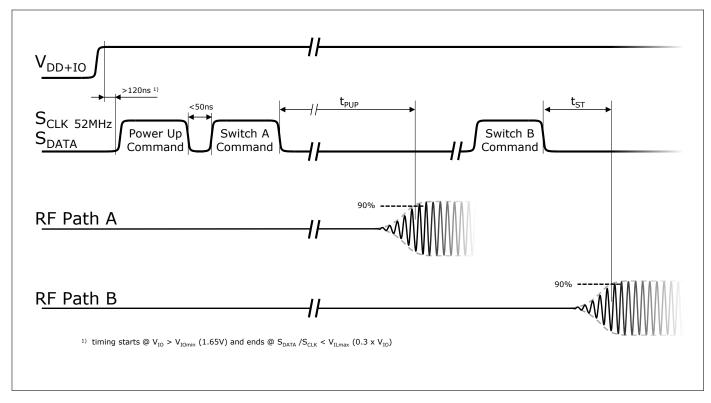


Figure 4: BGSA147ML10 Switching Time Behavior



**MIPI RFFE Specification** 

### Table 13: Register Mapping, Table I

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x00	REGISTER_0	7:0	MODE_CTRL	RF Switch Control	00000000	No	Yes Trigger 0-10	R/W
0x01	REGISTER_1	7:0	MODE_CTRL	RF Switch Control	00000000	No	Yes Trigger 0-10	R/W
0x1C	PM_TRIG	7	PWR_MODE(1)	0: Normal operation (ACTIVE)	1	Yes	No	R/W
			Operation Mode	1: Low Power Mode (LOW POWER)				
		6	PWR_MODE(0)	0: No action (ACTIVE)	0			
			State Bit Vector	1: Powered Reset (STARTUP to ACTIVE to LOW POWER)				
		5	TRIGGER_MASK_2	0: Data masked (held in shadow REG)	0	No		
				1: Data not masked (ready for transfer to active REG)				
		4	TRIGGER_MASK_1	0: Data masked (held in shadow REG)	0			
				1: Data not masked (ready for transfer to active REG)				
		3	TRIGGER_MASK_0	0: Data masked (held in shadow REG)	0	-		
				1: Data not masked (ready for transfer to active REG)				
		2	TRIGGER_2	0: No action (data held in shadow REG)	0	Yes		
				1: Data transferred to active REG				
		1	TRIGGER_1	0: No action (data held in shadow REG)	0			
				1: Data transferred to active REG				
		0	TRIGGER_0	0: No action (data held in shadow REG)	0			
				1: Data transferred to active REG				
0x1D	PRODUCT_ID	7:0	PRODUCT_ID	This is a read-only register. However, during the programming of the USID a write command sequence is performed on this register, even though the write does not change its value.	00110100	No	No	R
0x1E	MAN_ID	7:0	MANUFACTURER_ID [7:0]	This is a read-only register. However, during the programming of the USID, a write command sequence is performed on this register, even though the write does not change its value.	00011010	No	No	R
0x1F	MAN_USID	7:4	MANUFACTURER_ID [11:8]	These bits are read-only. However, dur- ing the programming of the USID, a write command sequence is performed on this register even though the write does not change its value.	0001			
		3:0	USID[3:0]	USID_Sel pin	See Tab. 10	No	No	R/W



### **MIPI RFFE Specification**

### Table 14: Register Mapping, Table II

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x20	EXT_PRODUCT_ID	EXT_PRODUCT_ID 7:0 EXT_PRODUCT_ID		Extension to PRODUCT_ID in register 0x1D. This is a read-only register. How- ever, during the programming of the USID a write command sequence is per- formed on this register, even though the	0000000	No	No	R
				write does not change its value.				
0x21	REV_ID	7:4	MAIN_REVISION	Chip main revision	0000	No	No	R
		3:0	SUB_REVISION	Chip sub revision	0000			
0x22	GSID	7:4	GSID0[3:0]	Primary Group Slave ID.	0000	No	No	R/W
		3:0	GSID1[3:0]	Secondary Group Slave ID.	0000			
0x23	UDR_RST	7	UDR_RST	Reset all configurable non-RFFE Re- served registers to default values. 0: Normal operation 1: Software reset	0	Yes	No	R/W
		6:0	RESERVED	Reserved for future use	0000000			
0x24	ERR_SUM	7	RESERVED	Reserved for future use	0	No	No	R
		6	COMMAND_FRAME_PARITY_ERR	Command Sequence received with par- ity error — discard command.	0			
		5	COMMAND_LENGTH_ERR	Command length error.	0			
		4	ADDRESS_FRAME_PARITY_ERR	Address frame with parity error.	0			
		3	DATA_FRAME_PARITY_ERR	Data frame with parity error.	0			
		2	READ_UNUSED_REG	Read command to an invalid address.	0			
		1	WRITE_UNUSED_REG	Write command to an invalid address.	0			
		0	BID_GID_ERR	Read command with a BROADCAST_ID or GROUP_ID.	0			
0x2B	BUS_LD	7:3	RESERVED	Reserved for future use	0x0	No	No	R/W
		2:0	BUS_LD[2:0]	Program the drive strength of the SDATA driver in readback modes. 0x0: 10 pF	0x4			
				0x1: 20 pF				
				0x2: 30 pF				
				0x3: 40 pF				
				0x4: 50 pF				
				0x5: 60 pF				
				0x6: 80 pF				
				0x7: 80 pF				
				0x8-0xF: Spare				



### **MIPI RFFE Specification**

### Table 15: Register Mapping, Table III

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x2D	EXT_TRIG_MASK	7	TRIGGER_MASK_10	0: Data writes to registers tied to EXT_TRIGGER_10 are masked. Data is held in shadow registers until the EXT_TRIGGER_10 bit is set to 1.	1	No	No	R/W
				1: Data writes to registers tied to EXT_TRIGGER_10 are not masked. Data writes go directly to the active registers.				
		6	TRIGGER_MASK_9	0: Data writes to registers tied to EXT_TRIGGER_9 are masked. Data is held in shadow registers until the EXT_TRIGGER_9 bit is set to 1.	1			
				1: Data writes to registers tied to EXT_TRIGGER_9 are not masked. Data writes go directly to the active registers.				
		5	TRIGGER_MASK_8	0: Data writes to registers tied to EXT_TRIGGER_8 are masked. Data is held in shadow registers until the EXT_TRIGGER_8 bit is set to 1.	1			
				1: Data writes to registers tied to EXT_TRIGGER_8 are not masked. Data writes go directly to the active registers.				
		4	TRIGGER_MASK_7	0: Data writes to registers tied to EXT_TRIGGER_7 are masked. Data is held in shadow registers until the EXT_TRIGGER_7 bit is set to 1.	1			
				<ol> <li>Data writes to registers tied to EXT_TRIGGER_7 are not masked. Data writes go directly to the active registers.</li> </ol>				
		3	TRIGGER_MASK_6	0: Data writes to registers tied to EXT_TRIGGER_6 are masked. Data is held in shadow registers until the EXT_TRIGGER_6 bit is set to 1.	1			
				<ol> <li>Data writes to registers tied to EXT_TRIGGER_6 are not masked. Data writes go directly to the active registers.</li> </ol>				
		2	TRIGGER_MASK_5	0: Data writes to registers tied to EXT_TRIGGER_5 are masked. Data is held in shadow registers until the EXT_TRIGGER_5 bit is set to 1.	1			
				<ol> <li>Data writes to registers tied to EXT_TRIGGER_5 are not masked. Data writes go directly to the active registers.</li> </ol>				
		1	TRIGGER_MASK_4	0: Data writes to registers tied to EXT_TRIGGER_4 are masked. Data is held in shadow registers until the EXT_TRIGGER_4 bit is set to 1.	1			
				<ol> <li>Data writes to registers tied to EXT_TRIGGER_4 are not masked. Data writes go directly to the active registers.</li> </ol>				
		0	TRIGGER_MASK_3	0: Data writes to registers tied to EXT_TRIGGER_3 are masked. Data is held in shadow registers until the EXT_TRIGGER_3 bit is set to 1.	1			
				<ol> <li>Data writes to registers tied to EXT_TRIGGER_3 are not masked. Data writes go directly to the active registers.</li> </ol>				



### **MIPI RFFE Specification**

### Table 16: Register Mapping, Table IV

Register Address	Register Name	Data Bits	Function	Description	Default	Broadcast_ID Support	Trigger Support	R/W
0x2E	EXT_TRIG	7	TRIGGER_10	0: No action. Data is held in shadow reg- isters.	0	Yes	No	R/W
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_10				
		6	TRIGGER_9	0: No action. Data is held in shadow reg- isters.	0			
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_9				
		5	TRIGGER_8	0: No action. Data is held in shadow reg- isters.	0	-		
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_8				
		4	TRIGGER_7	0: No action. Data is held in shadow reg- isters.	0	-		
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_7				
		3	TRIGGER_6	0: No action. Data is held in shadow reg- isters.	0	-		
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_6				
		2	TRIGGER_5	0: No action. Data is held in shadow reg- isters.	0	-		
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_5				
		1	TRIGGER_4	0: No action. Data is held in shadow reg- isters.	0			
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_4				
		0	TRIGGER_3	0: No action. Data is held in shadow reg- isters.	0			
				1: Data is transferred from shadow reg- isters to active registers for refisters tied to EXT_TRIGGER_3				



#### **MIPI RFFE Specification**

Warning: Register\_0 and Register\_1 RF switch control bits are identical. Writing both Registers Register\_0 and Register\_1 simultaneously will lead to undefined behavior. The unused register (Register\_0 or Register\_1) must remain 0x00.

State	Mode	D7	D6	D5	D4	D3	D2	D1	DO
0	ALL Series OFF (All Shunts OFF)	0	0	0	0	0	0	0	0
1	ALL Saries OFF (All Shunts ON)	1	1	1	1	0	0	0	0
2	RF1 Series	0	0	0	0	0	0	0	1
3	RF2 Series	0	0	0	0	0	0	1	0
4	RF3 Series	0	0	0	0	0	1	0	0
5	RF4 Series	0	0	0	0	1	0	0	0
6	RF1 Shunt	0	0	0	1	0	0	0	0
7	RF2 Shunt	0	0	1	0	0	0	0	0
8	RF3 Shunt	0	1	0	0	0	0	0	0
9	RF4 Shunt	1	0	0	0	0	0	0	0

#### Table 17: Modes of Operation (Truth Table, Register\_0)

Mapping of Switch Rows to Bit: ON = 1 OFF = 0

#### Table 18: Modes of Operation (Truth Table, Register\_1)

State	Mode	D7	D6	D5	D4	D3	D2	D1	DO
0	ALL Series OFF (All Shunts OFF)	0	0	0	0	0	0	0	0
1	ALL Series OFF (All Shunts ON)	1	1	1	1	0	0	0	0
2	RF1 Series	0	0	0	0	0	0	0	1
3	RF2 Series	0	0	0	0	0	0	1	0
4	RF3 Series	0	0	0	0	0	1	0	0
5	RF4 Series	0	0	0	0	1	0	0	0
6	RF1 Shunt	0	0	0	1	0	0	0	0
7	RF2 Shunt	0	0	1	0	0	0	0	0
8	RF3 Shunt	0	1	0	0	0	0	0	0
9	RF4 Shunt	1	0	0	0	0	0	0	0

#### Mapping of Switch Rows to Bit: ON = 1 OFF = 0

BGSA147ML10 truth table allows to connect any combination of above bits in one single write to register\_0 (respectively register\_1) command. As an example RF1 series can be set ON while RF1 shunt is set OFF, RF2, RF3 and RF4 series set OFF and shunt set ON by using this single write to register\_0 command «0b:11100001».



Application Information

## 7 Application Information

### **Pin Configuration and Function**

		RFC		
RF4	1	10	9	RF3
RF1	2		8	RF2
USID_Sel	3		7	GND
VIO	4	5	6	SCLK
•	Ş	SDATA		

Figure 5: BGSA147ML10 Pin Configuration (top view)

### Table 19: Pin Definition and Function

Pin No.	Name	Function	
1	RF4	RF4 port	
2	RF1	RF1 port	
3	USID_Sel	USID_Sel port (see Tab. 10 for 3 different USID States)	
4	VIO	RFFE Power Supply	
5	SDATA	MIPI RFFE DATA	
6	SCLK	MIPI RFFE CLOCK	
7	GND	Ground	
8	RF2	RF2 port	
9	RF3	RF3 port	
10	RFC	Common RF port	

## RESTRICTED

### BGSA147ML10

### **Ultra Low Resistance Antenna Tuning SP4T**



**Application Information** 

### **Evaluation Board Description**

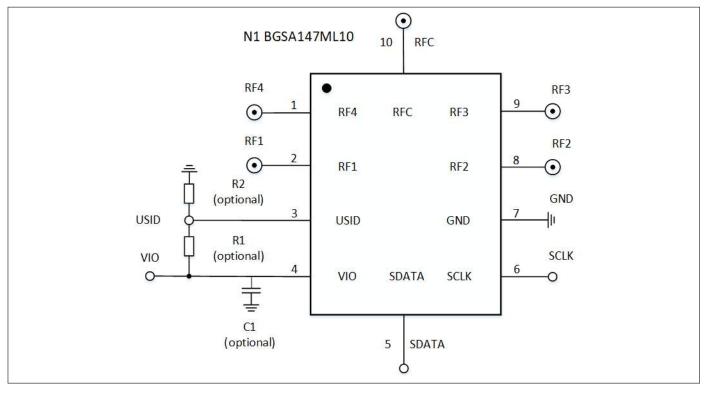


Figure 6: BGSA147ML10 Application Schematic

#### Table 20: Bill of Materials Table

Name	Part Type	Package	Manufacturer	Function
C1 (100pF optional)	Capacitor	0402	Various	De-coupling capacitor
N1	BGSA147ML10	TSLP-10-3	Infineon	Antenna Tuner
R1 (0 Ohm)	Resistor	0402	Various	Set USID default Address to 6 (VIO)
R2 (do not place)				
R2 (0 Ohm)	Resistor	0402	Various	Set USID default Address to 7 (GND)
R1 (do not place)				
R1 (do not place)	Resistor	0402	Various	Set USID default Address to 9 (FLOATING)
R2 (do not place)				

### Table 21: ESD robustness, System Level Test (SLT)

Parameter	Symbol	Symbol Values Unit		Values		Note / Test Condition
		Min.	Тур.	Max.		
ESD SLT <sup>1)</sup>	V <sub>ESD<sub>SLT</sub></sub>	-8	-	+8	kV	RF vs system GND, with 27 nH shunt inductor
ESD SLT <sup>1)</sup>	V <sub>ESD<sub>SLT</sub></sub>	-6	-	+6	kV	RF vs system GND, with 56 nH shunt inductor

<sup>1)</sup> IEC 61000-4-2 ( $R = 330 \Omega$ , C = 150 pF), contact discharge.



Package Information

## 8 Package Information

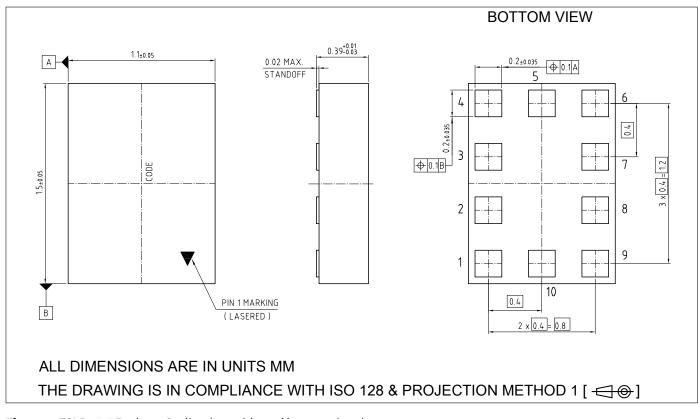


Figure 7: TSLP-10-3 Package Outline (top, side and bottom views)

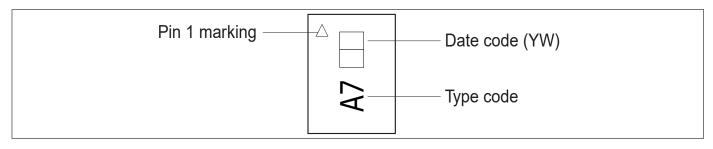


Figure 8: Marking Specification (top view): Date code digits Y and W defined in Table 22/23



**Package Information** 

Year	"Y"	Year	"Y"	Year	"Y"
2010	0	2020	0	2030	0
2011	1	2021	1	2031	1
2012	2	2022	2	2032	2
2013	3	2023	3	2033	3
2014	4	2024	4	2034	4
2015	5	2025	5	2035	5
2016	6	2026	6	2036	6
2017	7	2027	7	2037	7
2018	8	2028	8	2038	8
2019	9	2029	9	2039	9

### Table 22: Year date code marking - digit "Y"

Week	"W"								
1	A	12	Ν	23	4	34	h	45	v
2	В	13	Р	24	5	35	j	46	х
3	с	14	Q	25	6	36	k	47	у
4	D	15	R	26	7	37	l	48	z
5	E	16	S	27	а	38	n	49	8
6	F	17	Т	28	b	39	р	50	9
7	G	18	U	29	с	40	q	51	2
8	н	19	V	30	d	41	r	52	3
9	J	20	W	31	e	42	S	53	М
10	к	21	Y	32	f	43	t		
11	L	22	Z	33	g	44	u		



### **Package Information**

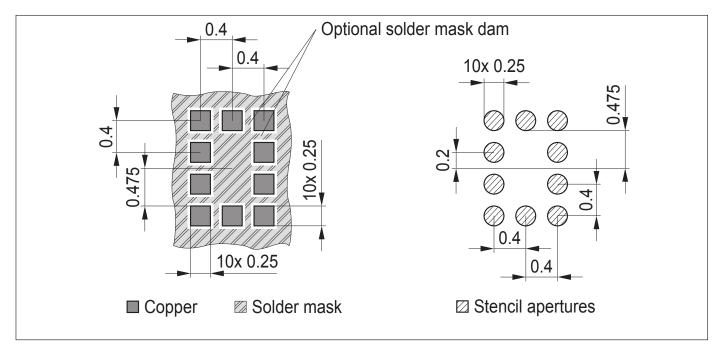


Figure 9: Footprint Recommendation (all dimensions are in units of mm)

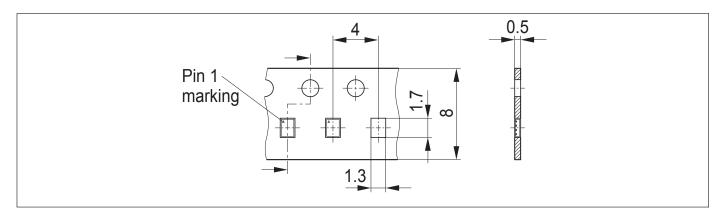


Figure 10: TSLP-10-3 Carrier Tape (all dimensions are in units of mm)

Revision History						
Page or Item	Subjects (major changes since previous revision)					
Revision 2.1, 2020	-12-22					
Cover page	Package height added					
20	Reference design and BOM added					

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Edition 2020-12-22 Published by Infineon Technologies AG 81726 Munich, Germany

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